Hybrid Crystal, 240 Hz to 110 MHz (-54B) 1.0 MHz to 70 MHz (-54BD), 1.0 MHz to 110 MHz (-54BE)





## **FEATURES**

- HCMOS, CMOS, NMOS, TTL, LS-TTL, S-TTL compatible
- Enabled output optional
- Hermetically sealed package

## **ELECTRICAL SPECIFICATIONS**

Operating Temperature Range: 0°C to 70°C.

Frequency Stability: (Inclusive of calibration tolerance at 25°C temperature change, input voltage change, load change, aging,

shock and vibration):  $\pm .01\%$  ( $\pm 100PPM$ ).

Input Voltage (Vdd):  $+5.0 \pm 0.5$  VDC.

input Current: 5 to 50 mA typical (see graph).

Rise Time: 4nS typical (CMOS levels), 2nS typical (TTL levels).

Fall Time: 4nS typical (CMOS levels), 2nS typical (TTL levels).

Logic '0' Level: 0.5 V maximum CMOS, 0.4 V maximum TTL

(Vdd = 5 V).

Logic '1' Level: 4.5 V minimum CMOS, 2.4 V minimum TTL

(Vdd = 5 V).

Logic '0' Sink Current: 16 mA minimum. Logic '1' Source Current: 0.4 mA minimum.

Output Waveform Symmetry: 60/40 standard. 55/45 available.

Output Load: 50 pF HCMOS or 1-10 TTL loads.

Enable Input Voltage: 3.5 V minimum. Disable Input Voltage: 0.5 V maximum. Enable Input Current: 10 µA maximum. Disable Input Current: 300 µA maximum.

## **MECHANICAL SPECIFICATIONS**

Hermetically Sealed Package: Leak rate less than

2 x 10<sup>-8</sup> atmosphere cc/sec. of helium. Marking Ink: Epoxy, solvent resistant. Solvent Resistance: Isopropyl alcohol,

trichloroethane, Freon TMC.

Terminal Solderability: Per MIL-STD-202, Method

208C.

## **ENVIRONMENTAL SPECIFICATIONS**

Temperature Cycle: - 55°C to + 85°C, 3 cycles. Shock: 1000 G's 0.35 millisecond, 1/2 sine wave, 3 shocks each plane.

Vibration: .06 D.A., 10-55 Hz, 35 G, 55-2000 Hz. Humidity: 85% relative humidity at 85°C, 240 hours.







